

**FEATURES**

- Large Detection Area
- Protective Cover Plate<sup>3</sup>
- Vacuum Compatible

**APPLICATIONS**

- Electron Detection
- X-ray Detection

**Electro-Optical Characteristics at 25 °C**

Parameters	Test Conditions	Min	Typ	Max	Units
Active Area	10 mm x 10 mm		100		mm <sup>2</sup>
Responsivity	(see graph on next page)	0.07	0.08	0.09	A/W
Shunt Resistance, Rsh	V = ± 10 mV	20			M-ohm
Capacitance, C	V <sub>R</sub> = 0 V		5	15	nF
Rise Time	V <sub>R</sub> = 0 V, R <sub>L</sub> = 50 Ω			10	usec

**Thermal Parameters**

Storage and Operating Temperature Range	Units
Ambient <sup>1</sup>	-10 ° to 40 °C
Nitrogen or Vacuum	-20 °C to 80 °C
Lead Soldering Temperature <sup>2</sup>	260 °C

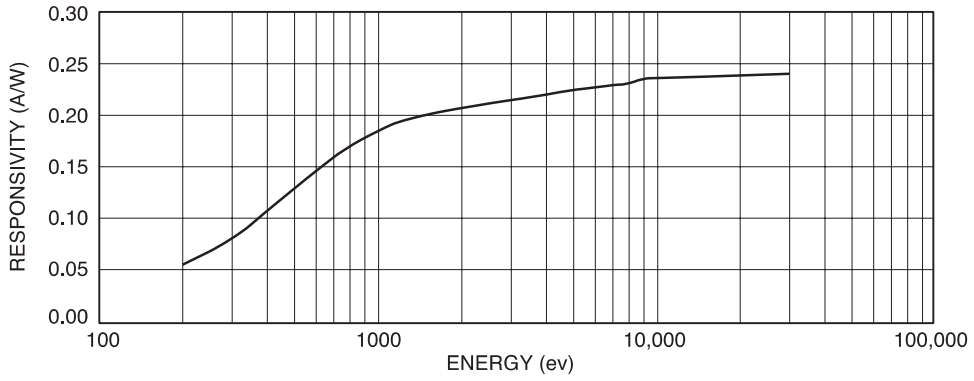
<sup>1</sup> Temperatures exceeding these parameters may create oxide growth on the active area.  
 Over time responsivity to low energy radiation and wavelengths below 150 nm will be compromised.

<sup>2</sup> 0.080" from case for 10 seconds.

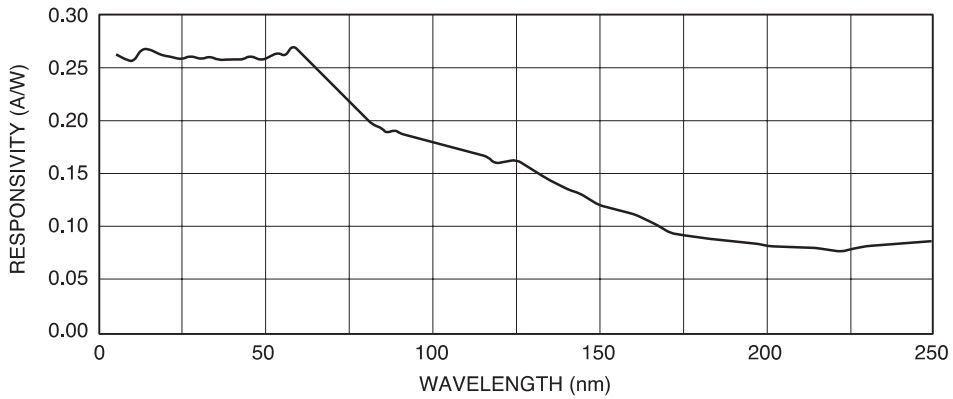
<sup>3</sup> Shipped with temporary cover to protect the photodiode array and wire bonds.  
 Review the Application Note, "Handling Precautions for AXUV, SXUV, and UVG Detectors", prior to removing cover.



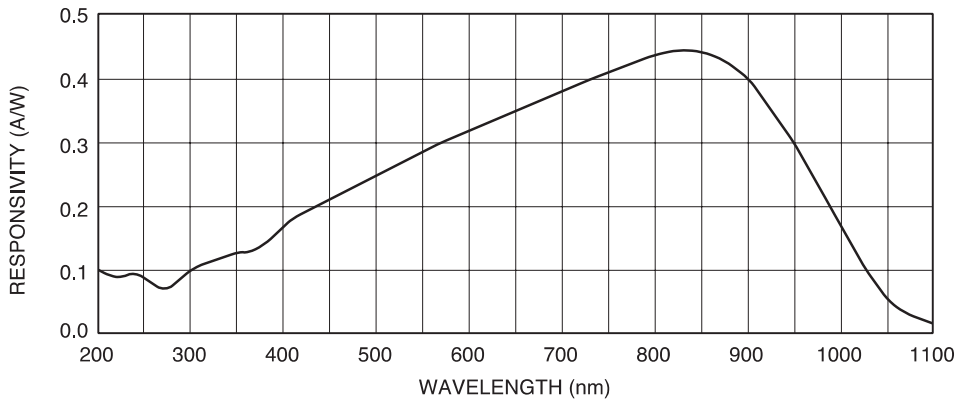
**Typical Electron Response**



**Typical EUV-UV Photon Response**

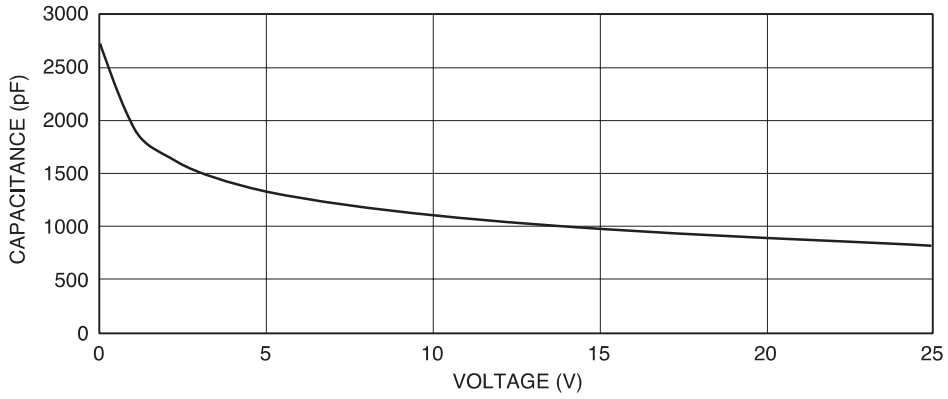


**Typical UV-VIS-NIR Photon Responsivity**

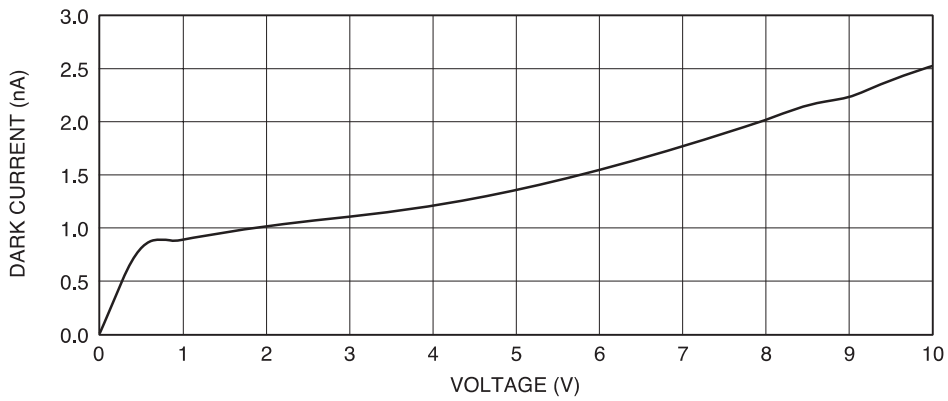




**Capacitance vs. Voltage**

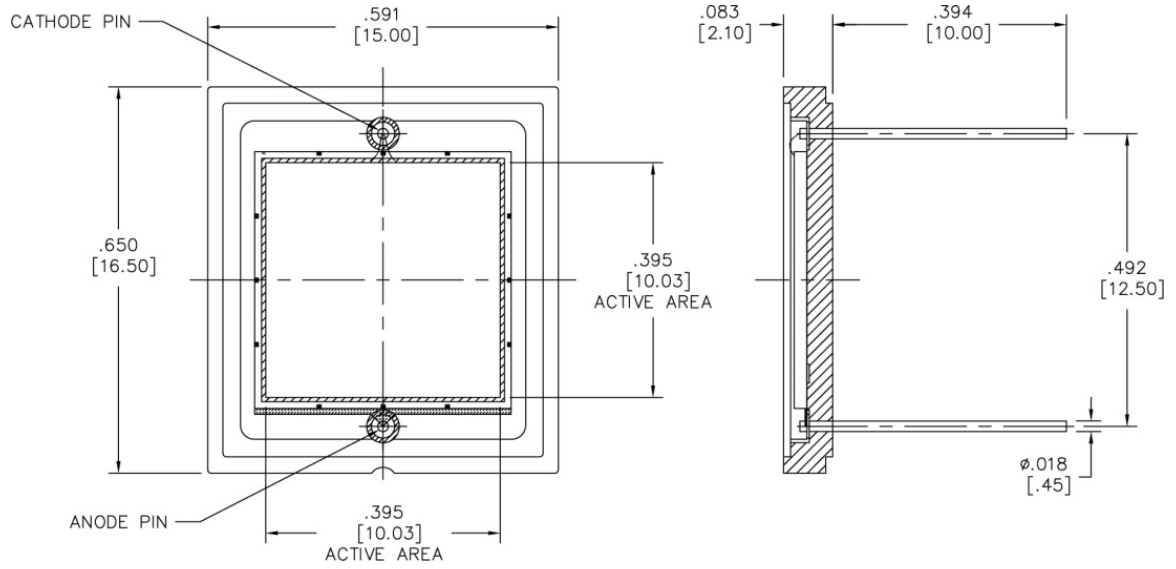


**Dark Current vs. Voltage**





**Package Information**



Dimensions are in inch [metric] units.

Specifications are subject to change without prior notice.